National Semiconductor

LMX5080 PLLatinum[™] 2.7 GHz Low Power Dual Modulus Prescaler for RF Personal Communications

Features

128/130

256/258

512/514

Applications

Cable TV tuners (CATV)

■ 2.7V to 5.5V operation

Low current consumption: 7 mA (typ) @ 5V

2.5 GHz wireless communications systems (ISM)

Direct Broadcast Satellite systems (DBS)

■ -40°C to +85°C low noise CMOS output

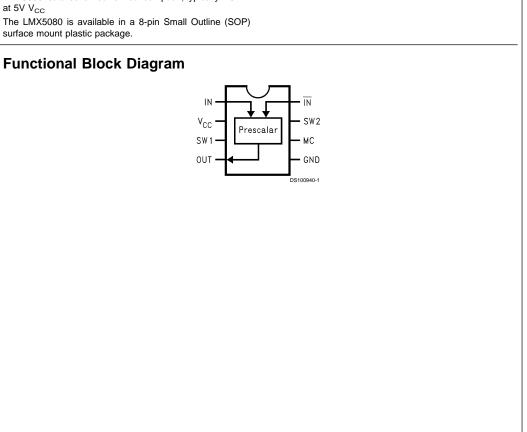
Selectable dual modulus prescaler

8-pin small package outline (SOP)

General Description

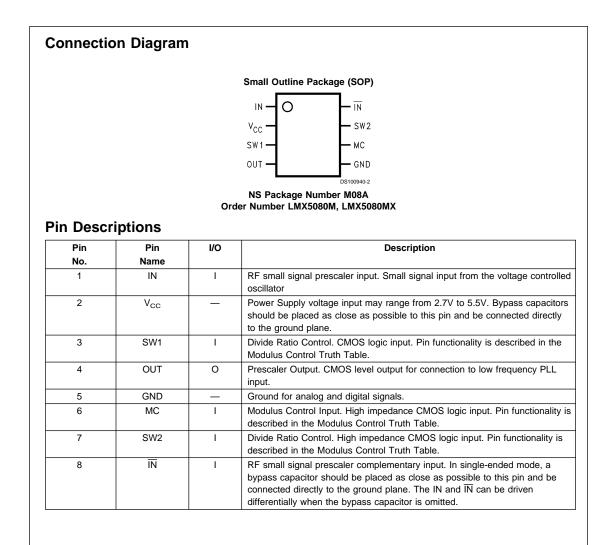
The LMX5080 integrated dual modulus prescaler, is designed to be used in a synthesized local oscillator for 2.5 GHz wireless transceivers. It is fabricated using National's 0.5µ ABiCV silicon BiCMOS process. The LMX5080 contains three dual modulus prescalers. Either a 128/130, 256/158 or a 512/514 prescaler can be selected for up to 2.7 Gz RF input frequencies. The prescaler inputs can be driven either differentially, or single ended with the use of a coupling capacitor on one of the inputs to ground. The LMX5080 CMOS output is optimized to generate very stable, low switching noise output signals. The LMX5080 prescaler can be used in conjunction with a low frequency Phase Lock Loop to form a frequency synthesizer suitable for UHF transceivers. Supply voltage can range from 2.7V to 5.5V. The LMX5080 features low current consumption; typically 7.0 mA at 5V V_{CC}

surface mount plastic package.



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2

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

	Value					
Parameter	Symbol	Min	Тур	Max	Units	
Power Supply Voltage	V _{cc}	-0.3		6.5	V	
Voltage on any pin with GND=0V	V _i	-0.3	Vc	_c +0.3	V	
Storage Temperature Range	Ts	-65		+1.50	°C	
Lead Temp. (solder 4 sec)	TL			+2.60	°C	

Recommended Operating

Conditions (Note 1)

			Value		
Parameter	Symbol	Min	Тур	Max	Units
Power Supply Voltage	V _{cc}	2.7		5.5	V
Operating Temperature	T _A	-40		+85	°C

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Recommended Operating Conditions indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. Electrical Characteristics document specific minimum and/or maximum performance values at specified test conditions and are guaranteed. Typ or Typical values are for informational purposes only which are based on design parameters or device characterization and are not guaranteed.

Note 2: This device is a high performance RF integrated circuit and is ESD sensitive. Handling and assembly of this device should only be done on ESD-free workstations.

Electrical Characteristics

(V_{CC} = 5.0V, T_A = -40°C to +85°C except as specified) (Note 1)

Symbol	Parameter	O an dition	Value			Unite
		Condition	Min	Тур	Max	Units
I _{cc}	Power Supply Current			7		mA
V _{OH}	Output Amplitude	$Z_{L} = 100 \text{ k}\Omega / / 10 \text{ pF}$	0.9 x V _{CC}			V
V _{OL}		$V_{\rm CC}$ = 2.7V to 5.5V			0.1 x V _{CC}	V
f _{in}	Input Frequency	AC coupled. V_{CC} = 2.7V to 5.5V	100		2700	MHz
Pf _{in}	Operational Input Signal Amplitude	V _{CC} = 2.7V to 5.5V	-15		+4	dBm
f _{out}	Output Frequency		0.1		25	MHz
V _{IH}	High-level Input Voltage (MC, SW1, SW2)		0.7 x V _{CC}			V
V _{IL}	Low-level Input Voltage (MC, SW1, SW2)				0.3 x V _{CC}	V
I _{IH}	High-level Input Current (MC, SW1, SW2)	$V_{IH} = 0.7 \times V_{CC}$		±1		uA
I _{IL}	Low-level Input Current (MC, SW1, SW2)	$V_{IL} = 0.3 \times V_{CC}$		±1		uA
t _{Set}	Modulus Control Set-up time. (Note 3)	SW1=H, SW2=H f _{in} = 2.7 GHz		15	20	ns
IM	Input/Output Intermodulation (Note 4)	-10 dBm / 50Ω AC coupled signal delivered to input. V _{CC} =2.7V to 5.5V. MC=0, MC=1. Fin=2.3 GHz to 2.5 GHz.		-35	-30	dBc

Note 3: See Timing Diagram.

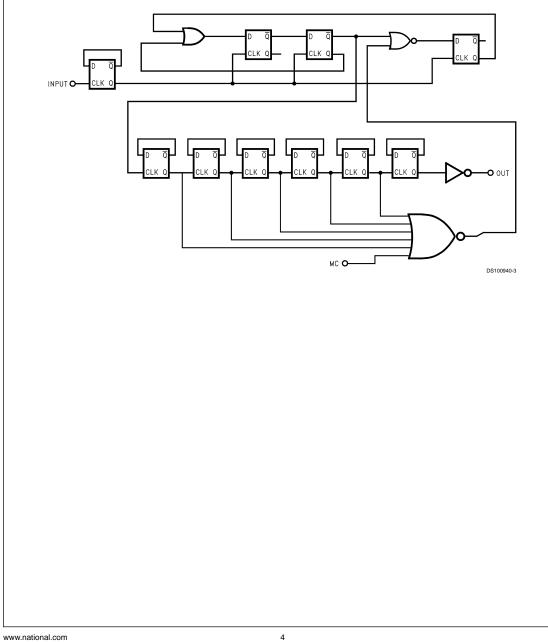
Note 4: Guaranteed by design and characterization, not tested. Output frequency measured at input.

3

Functional Description

The basic phase-lock-loop (PLL) configuration using an external prescaler consists of a high-stability crystal reference oscillator, a prescaler such as the National Semiconductor LMX5080, a low frequency synthesizer, a voltage controlled oscillator (VCO), and a loop filter. The frequency synthesizer typically includes programmable reference [R] and feedback [N] frequency dividers, a phase detector, as well as a charge pump. The MC signal is fed back to the prescaler from either the low frequency synthesizer, or a controller to set the prescaler divide ratio to N or N+2. The prescaler output frequency is established by dividing the VCO signal down via the prescaler modulus. The RF inputs to the prescalar consist of the Fin and /Fin input pins which are complementary inputs to a differential pair amplifier. This configuration can operate to 2 GHz with an input sensitivity of -15 dBm.

Block Diagram

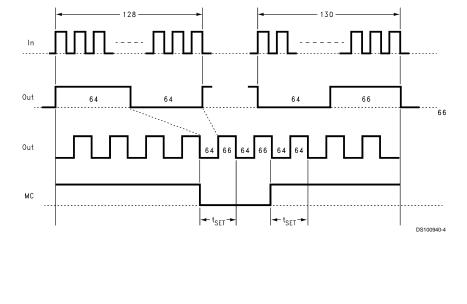




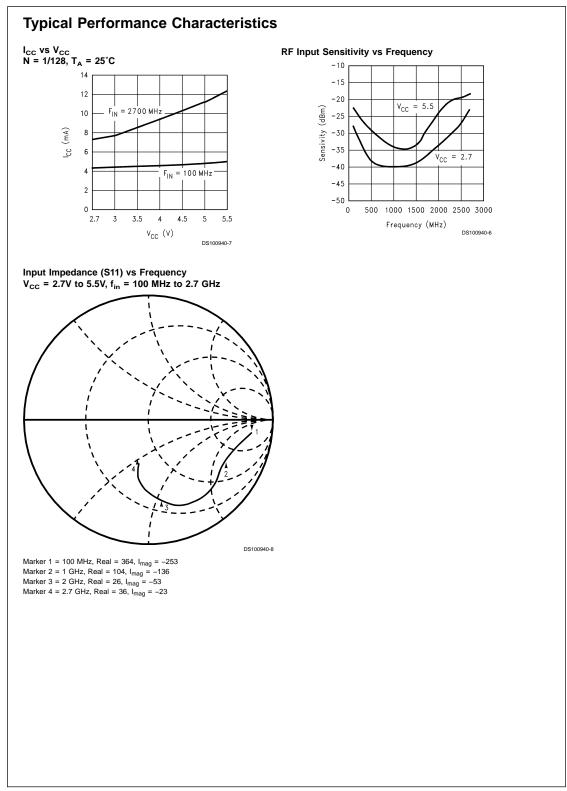
SW1	SW2	MC	Divide Ratio
Н	н	Н	1/128
н	н	L	1/130
Н	L	Н	1/256
L	н	Н	1/256
н	L	L	1/258
L	н	L	1/258
L	L	Н	1/512
L	L	L	1/514

Note: SW1, SW2, MC: H = 0.7 x V_{CC}, L = 0.3 x V_{CC}.



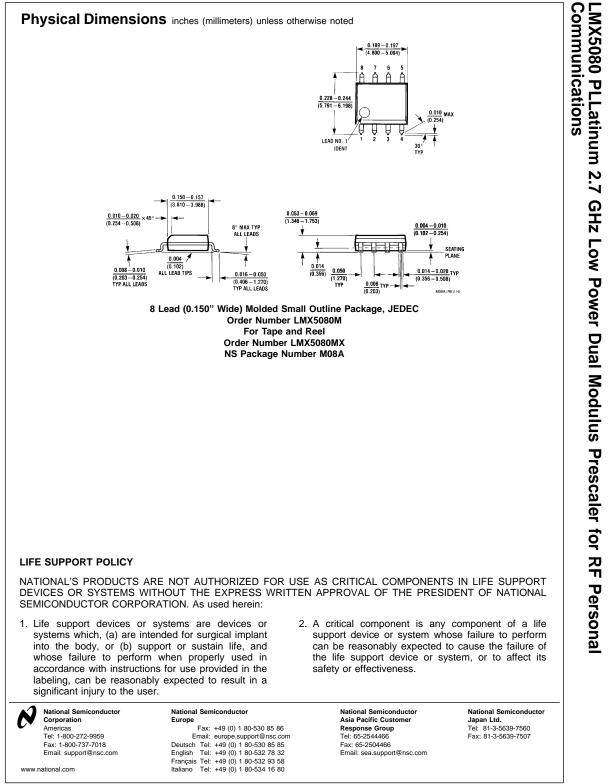


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6



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